PATENT COOPERATION TREATY

INTERNATIONAL PRELIMINARY REPORT ON PATENTABILITY

(Chapter II of the Patent Cooperation Treaty)

(PCT Artcle 36 and Rule 70)

Applicant's or agent's file reference PH-21532-PCT	FOR FURTHER ACT	ON	See Form PCT/IPEA/41	6		
International application No.	International filing date(da	y/month/year)	Priority date (day/month/y	ear)		
PCT/KR2004/000374	24 FEBRUARY 200	4 (24.02.2004)	09 JUNE 2003 (09.06.20			
International Patent Classification (IPC)						
IPC7 H01L 33/00						
Applicant POSTECH FOUNDATION et	t al					
1 THE CONTRACT OF THE CONTRACT	1::	antablished by this 1	nto-national Proliminator Com-			
This report is the international pre Authority under Article 35 and tra			ntemational Freilminary Exa	uning		
2. This REPORT consists of a total of	of 4 sheets, i	ncluding this cover sh	eet.			
3. This report is also accompanied by) a total of	sheets, as follows:			
a. (sent to the applicant and to the International Bureau) a total ofsheets, as follows: sheets of the description, claims and/or drawings which have been amended and are the basis for this report						
and/or sheets con	and/or sheets containing rectifications authorized by this Authority (see Rule 70.16 and Section 607 of the					
	Administrative Instructions). sheets which supersede earlier sheets, but which this Authority considers contain an amendment that goes					
beyond the disclosure in the international application as filed, as indicated in item 4 of Box No. 1 and the						
	Supplemental Box. b. (sent to the International Bureau only) a total of (indicate type and number of electronic carrier(s))					
containing a sequence li	containing a sequence listing and/or tables related thereto, in computer readable form only, as indicated in the Supplemental Box relating to Sequence Listing (see Section 802 of the Administrative Instructions).					
Supplemental Box relati	ng to Sequence Listing (see	Section 802 of the Ad	iministrative instructions).			
4. This report contains indications re	elating to the following item	s:				
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Box No. II Priority						
Box No. III Non-estable	Box No. III Non-establishment of opinion with regard to novelty, inventive step and industrial applicability					
Box No. V Reasoned scitations and	Box No. V Reasoned statement under Article 35(2) with regard to novelty, inventive step or industrial applicability; citations and explanations supporting such statement					
Box No. VII Certain defi	Box No. VII Certain defects in the international application					
Box No. VIII Certain obs	ervations on the internation	al application				
Data of submission of the demand		Date of completion of	f this report			
Date of submission of the demand		Date of completion of	uno report			
06 JANUARY 2005	(06.01.2005)	27 SEPTEM	BER 2005 (27.09.2005)			
Name and mailing address of the IPEA	/KR	Authorized officer		NIME AND		
Korean Intellectual Propert 920 Dunsan-dong, Seo-gu, Republic of Korea	ty Office	KIM, Dong Yu	p .			
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INTERNATIONAL PRELIMINARY REPORT ON PATENTABILITY

International application No. PCT/KR2004/000374

Вс	x No.	o. 1 Basis of the report	
1.		ith regard to the language, this report is based on the international and therwise indicated under this item. This report is based on translations from the original language is which is the language of a translation furnished for the purposes international search (under Rules 12.3 and 23.1(b)) publication of the international application (under Rules 13.2 international preliminary examination (under Rules 55.2 international preliminary examination)	of: 2.4)
2.	to the	th regard to the elements of the international application, this report the receiving Office in response to an invitation under Article 14 are nexed to this report): the international application as originally filed/furnished	
		pages*received by	as originally filed/furnished this Authority on this Authority on
			as originally filed/furnished as amended (together with any statment) under Article 19 this Authority on this Authority on
		the drawings: pages	this Authority on
3.		The amendments have resulted in the cancellation of: the description, pages the claims, Nos. the drawings, sheets the sequence listing (specify): any table(s) related to sequence listing (specify):	
4.		This report has been established as if (some of) the amendments made, since they have been considered to go beyond the disclost (Rule 70.2(c)). the description, pages the claims, Nos. the drawings, sheets the sequence listing (specify): any table(s) related to sequence listing (specify):	are as filed, as indicated in the Supplemental Box
*	If item	em 4 applies, some or all of those sheets may be marked "supersede	d."

INTERNATIONAL PRELIMINARY REPORT ON PATENTABILITY

International application No. PCT/KR2004/000374

Box No. V Reasoned statement under Article 35(2) with regard to novelty, inventive step or industrial applicability; citations and explanations supporting such statement

Statement			
Novelty (N)	Claims 1-1	15	YE:
	Claims NO	ONE	NO
Inventive step (IS)	Claims 7-8	8, 14-15	YE
	Claims 1-6	6, 9-13	NO
Industrial applicability (IA)	Claims 1-1	15	YE
	Claims NO	ONE	NO

2. Citations and explanations (Rule 70.7)

(1) The documents cited in the International Search Report are as follows:

D1: KR 2003-85272 A

D2: JP 2003-73859 A

D3: WO 94/00885 A1

D4: JP 2003-45661 A

D5: JP 2000-31462 A

(2) Novelty

The subject-matter of claims 1-15 is considered to be new under PCT Article 33(2).

(3) Inventive Step

Claims 1-6

The subject-matter of claims 1-6 is about a contact fabric using a heterostructure of metal/semiconductor nanorods comprising: semiconductor nanorods; and metals deposited on semiconductor nanorods wherein there is a low contact resistance ohmic characteristic or a rectifying Schottky characteristic between the nanorods and the metals

D2 discloses a regularly arranged nano-structure(7) joined on the substrate(1). The substance forming the nano-structure such as TiO₂ or ZnO can develop photocatalyst characteristics when absorbing at least ultraviolet radiation or the ultra-violet of sun light. The regularly arranged nano-structure is obtained on the substrate, which has a morphology such as nanotube, nanodot, nano drill rod, nano fiber, and nano wire. (the abstract, figures 1, 2 of D1)

D3 discloses a light emitting device incorporating a layer of porous silicon of low dimensionality surmounted by a discontinuous layer of silver in the form of discrete islands. A digitated electrode is connected to the islands, and the islands have diameters in the range of 5 nm to 20 nm and spacings in the range of 10 nm to 50 nm. They form a Schottky diode structure on the silicon. (the abstract of D2)

Therefore, the technical features of claims 1-6 are already disclosed in D2 and D3 in a similar field of application, or are included among several straightforward possibilities or combinations from which the skilled person could select without the exercise of inventive skill.

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Supplemental Box

In case the space in any of the preceding boxes is not sufficient. Continuation of:

BOX V.

Claims 9-13

The subject-matter of claims 9-13 is about a method for manufacturing a contact fabric using a heterostructure of metal/semiconductor nanorods. The method comprises a step for making a nanorods, and a step for depositing metals on the nanorods, wherein there is a low contact resistance ohmic characteristic or a rectifying Schottky characteristics between the nanorods and the metals.

D2 discloses a manufacturing method of a regularly arranged nano-structure joined on the substrate. The substance for forming the nano-structure, the size and the distribution of nanorods, the substance of electrodes, and the characteristic of nanorods are disclosed in D2.

D3 discloses a manufacturing method of a light emitting device incorporating a layer of porous silicon of low dimensionality surmounted by a discontinuous layer of silver in the form of discrete islands. A digitated electrode is connected to the islands, and the islands have diameters in the range of 5 nm to 20 nm. The nanorods form Schottky diode structures on the silicon.

Therefore, the features of 9-13 are already disclosed in D2 and D3 in a similar field of application, or are included among several straightforward possibilities or combinations from which the skilled person could select without the exercise of inventive skill.

Consequently, the subject-matter of claims 1-6, 9-13 lacks an inventive step under PCT Article 33(3)

Claims 7-8 and 14-15

The subject-matter of Claims 7 and 14 is about a contact fabric and a method for manufacturing a contact fabric containing Au or Pt layer formed on the metal layer.

And the subject-matter of Claims 8 and 15 is about a contact fabric which is heat treated for the development of the electrical characteristic and a method for manufacturing a contact fabric containing an extra heat treatment step.

But none of the documents D1-D5 refer to the above-mentioned technical features.

Consequently, the subject-matter of claims 7-8 and 14-15 is believed to have an inventive step under PCT Article 33(3).

(4) Industrial Applicability

The subject matter of Claims 1-15 is considered to be industrially applicable under PCT Article 33(4).